

# DAS-PMAS5B

## P-Type Mono Cell

### Product Feature

- ◇ High conversion efficiency , Up to 22.0%
- ◇ Light Induced Degradation  $\leq 2.5\%$
- ◇ PID resistant
- ◇ Power temperature coefficient  $\leq -0.38\%/^{\circ}\text{C}$
- ◇ Relative conversion efficiency ( $200\text{W}/\text{m}^2$ )  $\geq 95\%$

### Quality Control

- ◇ The accuracy of the efficiency test is controlled at  $\pm 0.1\%$
- ◇ IV/EL/Appearance 100% automatic inspection
- ◇ Calibration Cell source to Fraunhofer ISE

### Management System Certification

- ◇ ISO 9001:2015 Quality Management System
- ◇ ISO 14001:2015 Environmental Management System
- ◇ ISO 45001:2018 Occupational Health and Safety Management System

## Product Features

Dimension:	158.75mmx158.75mm±0.25mm
Cell Thickness:	180μm±20μm
Front side:	0.7±0.1mm wide bus bars, 110 finger grids, SiN
Back side:	2.0±0.1 mm wide discontinuous soldering pads, Aluminum back surface field

## Temperature Coefficients

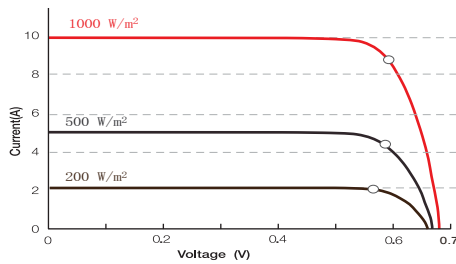
Current Temperature Coefficient	Tkcurrent: +0.048 %/K
Voltage Temperature Coefficient	Tkvoltage: -0.31 %/K
Power Temperature Coefficient	Tkpower: -0.38 %/K

## Electric Performance

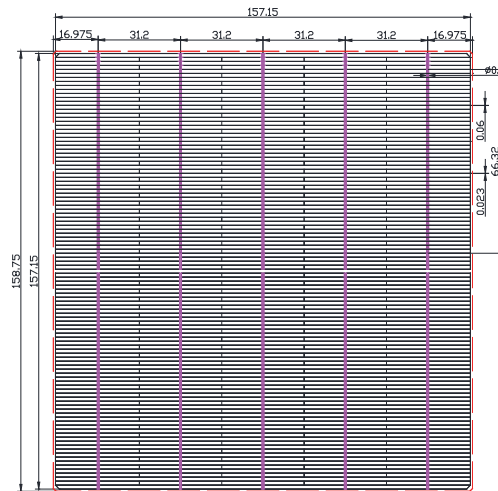
Eff(%)	Pmpp(W)	Ump(V)	Imp(A)	Uoc(V)	Isc(A)	FF(%)
22.30%	5.62	0.576	9.752	0.678	10.237	81.16
22.20%	5.59	0.575	9.717	0.677	10.222	81.05
22.10%	5.57	0.574	9.694	0.676	10.210	80.92
22.00%	5.54	0.573	9.682	0.675	10.200	80.78
21.90%	5.52	0.572	9.659	0.674	10.183	80.70
21.80%	5.49	0.571	9.638	0.673	10.169	80.59
21.70%	5.47	0.569	9.618	0.672	10.149	80.48
21.60%	5.44	0.567	9.603	0.671	10.144	80.39
21.50%	5.42	0.565	9.584	0.670	10.122	80.32
21.40%	5.39	0.564	9.572	0.669	10.108	80.16
21.30%	5.37	0.563	9.538	0.668	10.083	80.00

- Standard Test Conditions: 1000W/ m<sup>2</sup>, AM 1.5, 25°C
- Specifications and data are only for reference.

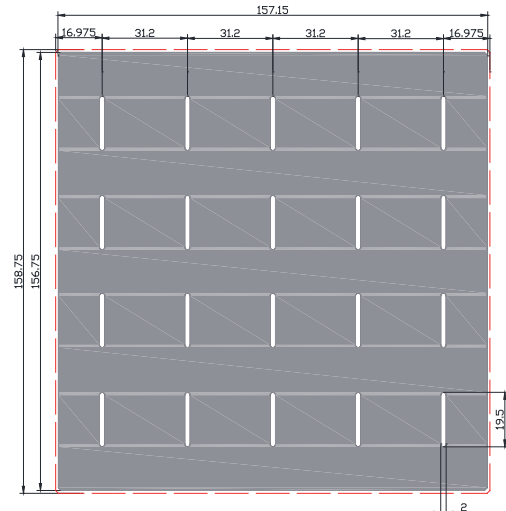
## IV Curve



## Front side



## Rear side



## Spectral Response (SR)

